



INFORMATION DISCLOSURE STATEMENT

Applicant : Chan-Yong Park
App. No : 10/802,593
Filed : March 17, 2004
For : PHOTO-DIODE HAVING A CHARGE
DENSITY PORTION IN A FIELD
CONTROLLING LAYER AND METHOD
FOR FABRICATING THE SAME
(As amended)
Examiner : Thomas L. Dickey
Art Unit : 2826

CERTIFICATE OF MAILING

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first-class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

September 19, 2005

(Date)

Mincheol Kim, Reg. No. 51,306

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application is a PTO/SB/08 Equivalent listing 3 references to be considered by the Examiner. Also enclosed are 2 references which are non-patent literature as listed on the Information Disclosure Statement.

This Information Disclosure Statement is being filed before the mailing date of a final action and before the mailing of a Notice of Allowance. This Statement is accompanied by the fees set forth in 37 C.F.R. § 1.17(p). The Commissioner is hereby authorized to charge any additional fees which may be required or to credit any overpayment to Account No. 11-1410.

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Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: September 19, 2005

By:


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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Multiple sheets used when necessary)

SHEET 1 OF 1

Application No.	10/802,593
Filing Date	March 17, 2004
First Named Inventor	Chan-Yong Park
Art Unit	2826
Examiner	Thomas L. Dickey
Attorney Docket No.	GAIN3.001AUS

U.S. PATENT DOCUMENTS

Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
	1	US 4,326,211	04/20/1982	Eugenius T.J.M. Smeets	

NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
	2	I. Watanabe et al., "Gain-Bandwidth Product Analysis of InAlGaAs-InAlAs Superlattice Avalanche Photodiodes" IEEE Photonics Technology Letters, Vol. 8, No. 2, pp. 269-271, 1996	
	3	C.Y. Park et al., "Fabrication Of InGaAs/InP Avalanche Photodiodes By Reactive Ion Etching Using CH ₄ /H ₂ Gases", Journal of Vacuum Science Technologies B, Vol. 13, No. 3, pp. 974-977, 1995	
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	5		
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Examiner Signature	Date Considered
<p>*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</p>	

T¹ - Place a check mark in this area when an English language Translation is attached.